



Atty. Docket No. 8013-1006

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Masaru KURAMOTO et al.

Confirmation No. 9452

Serial No. 10/091,437

GROUP 2822

Filed March 7, 2002

Examiner Maria F. Guerrero

GROUP III-V COMPOUND SEMICONDUCTOR
CRYSTAL STRUCTURE AND METHOD OF
EPITAXIAL GROWTH OF THE SAME AS
WELL AS SEMICONDUCTOR DEVICE
INCLUDING THE SAME

AMENDMENT

Commissioner for Patents

Washington, D.C. 20231

Sir:

Responsive to the Official Action of December 31, 2002,
please amend the above-identified application as follows:

IN THE CLAIMS:

Cancel claims 1-17.

REMARKS

Responsive to the requirement for restriction,
applicants elect Group II, claims 18-57, drawn to semiconductor
devices, without traverse.

Non-elected claims 1-17 are cancelled herewith, but may
be made the subject of a divisional application to be filed at
any time during the pendency of the present application.

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